Ordering number:EN4313

N-Channel Silicon MOSFET

2SK1924

Ultrahigh-Speed Switching Applications

DISCONTINUED PRODUCT

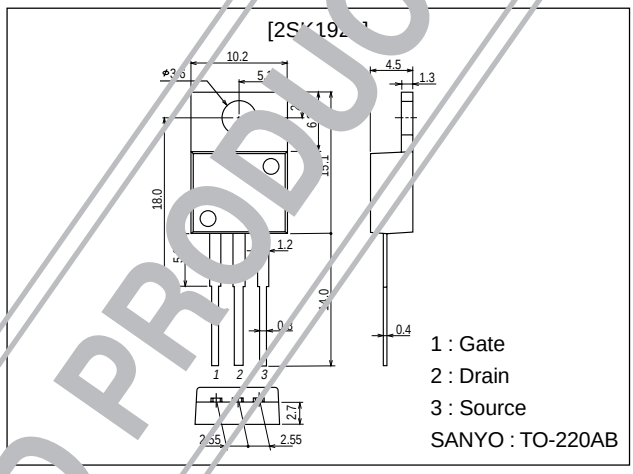
Features

- Low ON resistance.
- Ultrahigh-speed switching.
- High-speed diode (trr=140ns).

Package Dimensions

unit:mm

2052C



Specifications

Absolute Maximum Ratings at Ta = 25˚C

Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	V_{DSS}		600	V
Gate-to-Source Voltage	V_{GSS}		±30	V
Drain Current (DC)	I_D		6	A
Drain Current (pulse)	I_{DP}		24	A
Allowable Power Dissipation	P_D		1.75	W
		Tc=25˚C	70	W
Channel Temperature	Tch		150	˚C
Storage Temperature	Tstg		–55 to +150	˚C

Electrical Characteristics at Ta = 25˚C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Drain-to-Source Breakdown Voltage	$V_{(BR)DSS}$	I_D=10mA, V_{GS}=0	600			V
Zero-Gate Votlage Drain Current	I_{DSS}	V_{DS}=480V, V_{GS}=0			1.0	mA
Gate-to-Source Leakage Current	I_{GSS}	V_{GS}=±30V, V_{DS}=0			±100	nA
Cutoff Voltage	$V_{GS(off)}$	V_{DS}=10V, I_D=1mA	2.0		3.0	V
Forward Transfer Admittance	|yfs|	V_{DS}=10V, I_D=3A	2.3	4.5		S
Static Drain-to-Source On-State Resistance	$R_{DS(on)}$	I_D=3A, V_{GS}=10V		1.1	1.5	Ω

(Note) Be careful in handling the 2SK1924 because it has no protection diode between gate and source.

Continued on next page.

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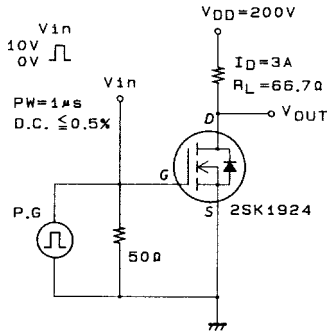
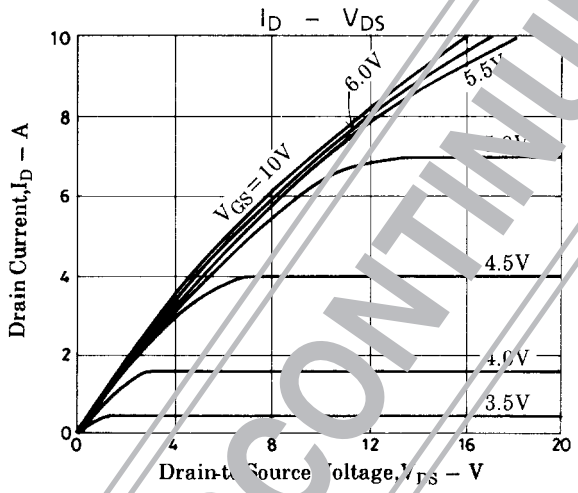
SANYO Electric Co.,Ltd. Semiconductor Company
TOKYO OFFICE Tokyo Bldg., 1-10, 1 Chome, Ueno, Taito-ku, TOKYO, 110-8534 JAPAN

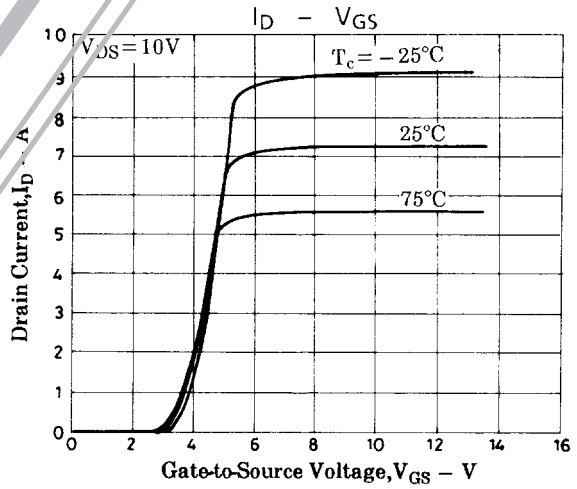
Continued from preceding page.

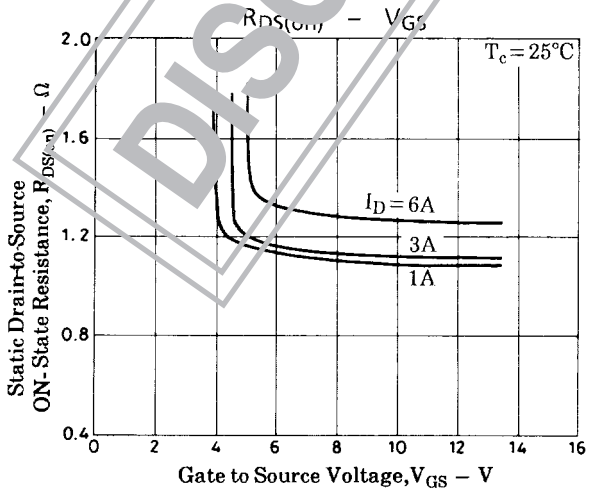
Parameter	Symbol	Conditions	Ratings			Unit
Input Capacitance	Ciss	V_{DS}=20V, f=1MHz		1100		pF
Output Capacitance	Coss	V_{DS}=20V, f=1MHz		150		pF
Reverse Transfer Capacitance	Crss	V_{DS}=20V, f=1MHz		45		pF
Turn-ON Delay Time	$t_{d(on)}$	See specified Test Circuit.		18		ns
Rise Time	t_r	See specified Test Circuit.		25		ns
Turn-OFF Delay Time	$t_{d(off)}$	See specified Test Circuit.		240		ns
Fall Time	t_f	See specified Test Circuit.		60		ns
Diode Forward Voltage	V_{SD}	I_S=6A, V_{GS}=0			1.5	V
Diode Reverse Recovery Time	trr	I_S=6A, di/dt=100A/μs		140		ns

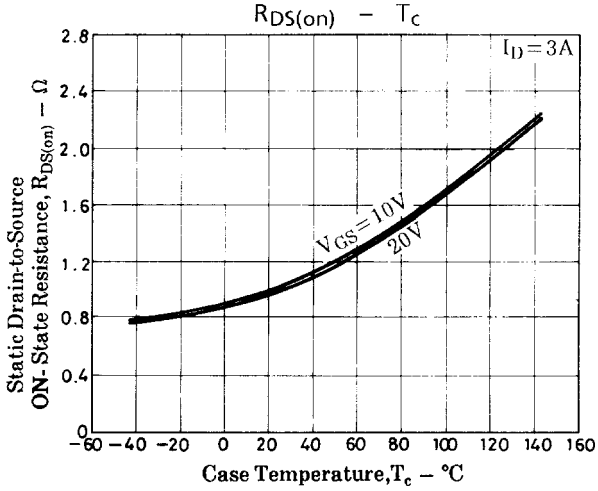
Switching Time Test Circuit











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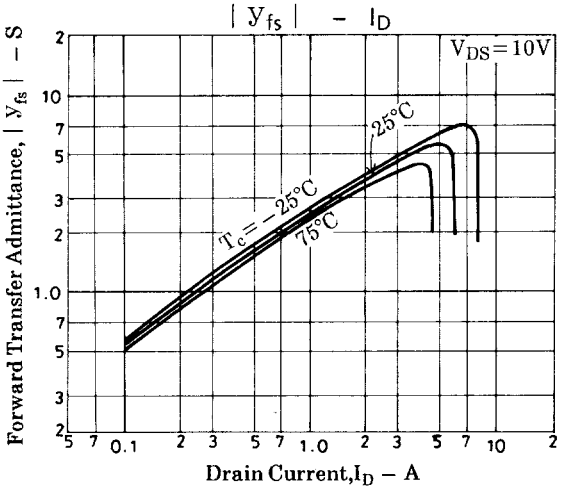

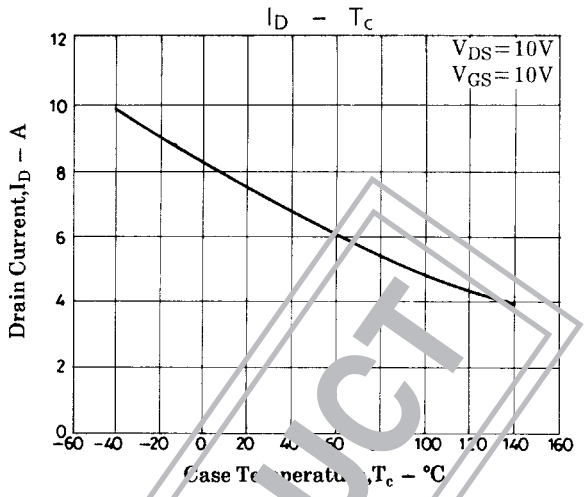

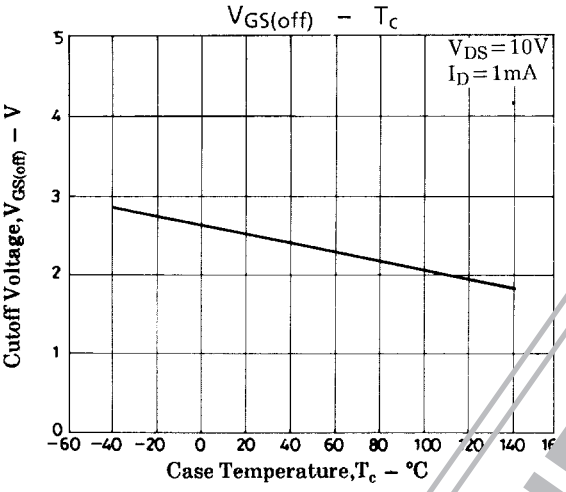

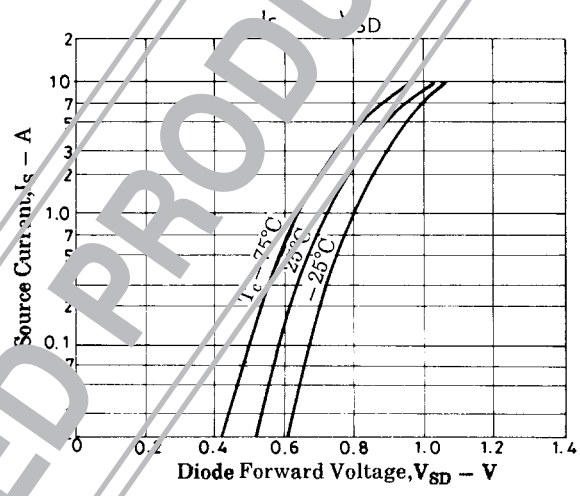

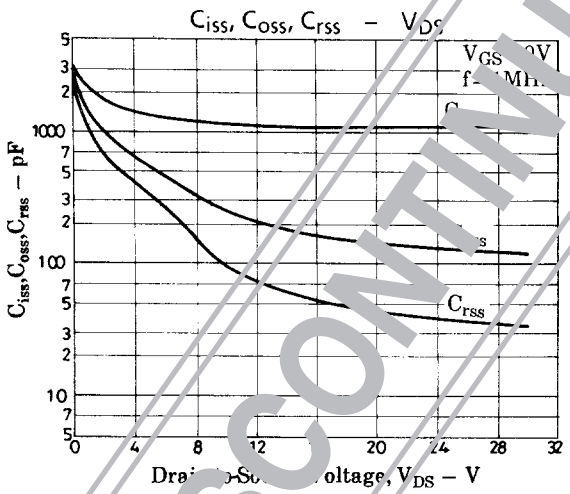

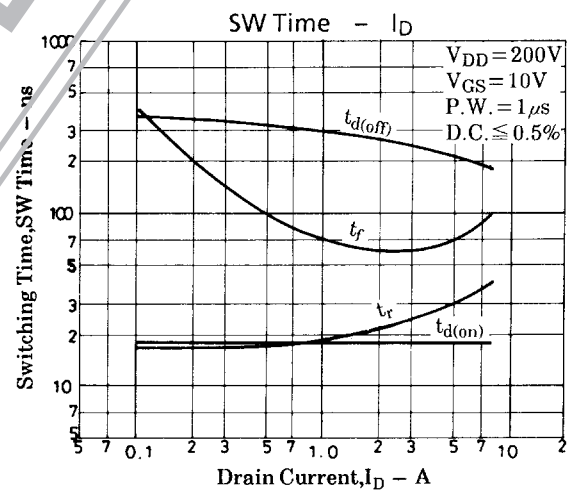

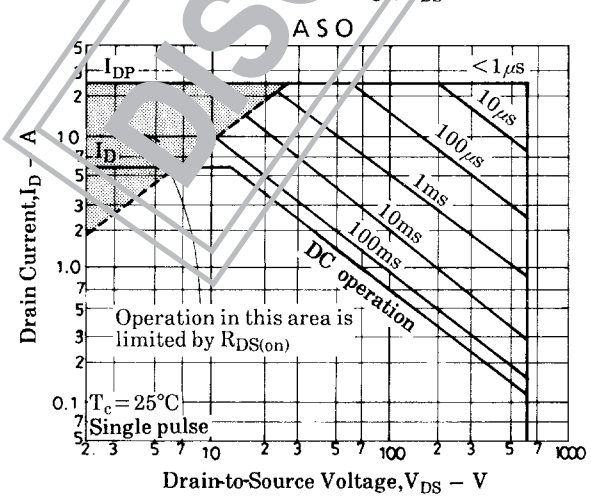

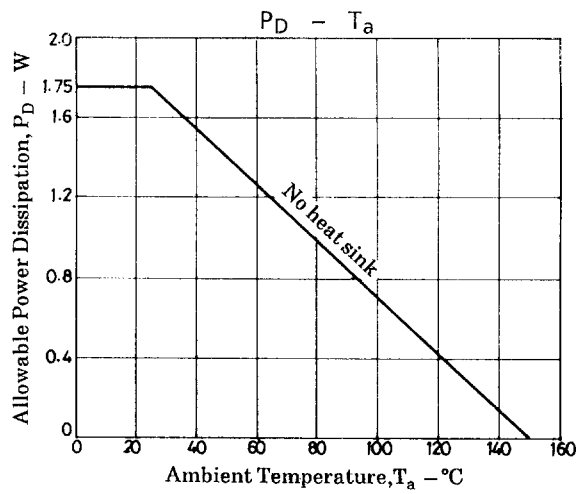

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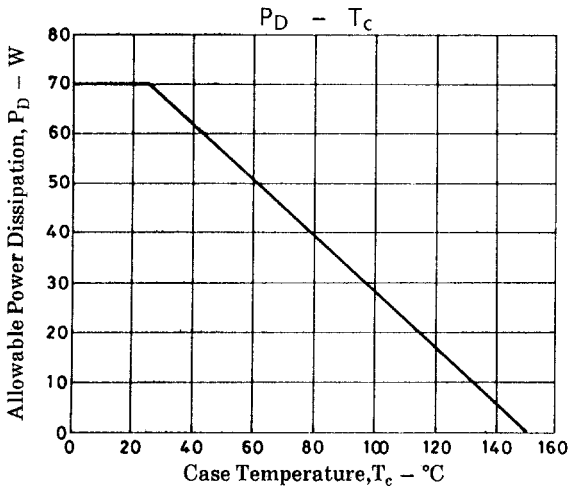

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